



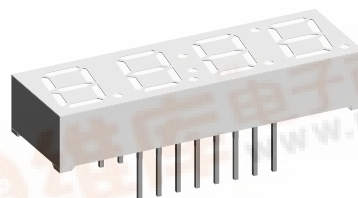
TDCG / R / Y10..m

Vishay Semiconductors

Clock Display

Description

Four digit Display, with 10 mm digit charactersize.
Designed as clock Display with active colon between digit two and three.



16770



Features

- High efficient AlInGAP technology
- Dark surface, white segments
- Common anode (TDC.1050m)
- Common cathode (TDC.1060m)
- Recommended viewing distance up to 7 meter
- Multiplex mode
- Lead-free device

Applications

Clock modules for Video/Audioequipment,
Instrumentation, Set Top Boxes

Parts Table

Part	Color, Luminous Intensity	Circuitry
TDCG1050m	Green, $I_V = (2.8 \text{ to } 4.0) \text{ mcd}$	Common anode
TDCG1060m	Green, $I_V = (2.8 \text{ to } 4.0) \text{ mcd}$	Common cathode
TDCR1050m	Red, $I_V = (4.0 \text{ to } 6.0) \text{ mcd}$	Common anode
TDCR1060m	Red, $I_V = (4.0 \text{ to } 6.0) \text{ mcd}$	Common cathode
TDCY1050m	Super Yellow, $I_V = (4.0 \text{ to } 8.0) \text{ mcd}$	Common anode
TDCY1060m	Super Yellow, $I_V = (4.0 \text{ to } 8.0) \text{ mcd}$	Common cathode

Absolute Maximum Ratings

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

TDCG1050m/ TDCG1060m, TDCR1050m/ TDCR1060m, TDCY1050m/ TDCY1060m,

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	5	V
Forward current		I_F	25	mA
Operating temperature range		T_{amb}	- 40 to + 85	$^\circ\text{C}$
Storage temperature range		T_{stg}	- 40 to + 100	$^\circ\text{C}$
Soldering temperature		T_{sd}	260 ± 5	$^\circ\text{C}$
Power dissipation		P_V	60	mW
Peak forward current	(Duty 1/10 @ 1kHz)	$I_F(\text{Peak})$	160	mA

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Optical and Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Red

TDCR1050m/ TDCR1060m

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity per segment ¹⁾	I _F = 2 mA	TDCR1050m	I _V		1.5		mcd
		TDCR1060m	I _V		1.5		mcd
	I _F = 10 mA	TDCR1050m	I _V	4.0	6.0		mcd
		TDCR1060m	I _V	4.0	6.0		mcd
Luminous intensity of colon	I _F = 2 mA	TDCR1050m	I _V		0.4		mcd
		TDCR1060m	I _V		0.4		mcd
	I _F = 10 mA	TDCR1050m	I _V	0.5	0.8		mcd
		TDCR1060m	I _V	0.5	0.8		mcd
Dominant wavelength	I _F = 20 mA		λ _d		631		nm
Peak wavelength	I _F = 20 mA		λ _p		639		nm
Spectral bandwidth	I _F = 20 mA		Δλ		20		nm
Forward voltage	I _F = 20 mA		V _F		2.0	2.4	V
Reverse current	V _R = 5 V		I _R			10	μA

Note¹⁾ I_{Vmin} and I_V groups are mean values of all segments (a to g, D1 to D4),
matching factor within segments is ≥ 0.5, excluding decimal points and colon.

Yellow

TDCY1050m/ TDCY1060m

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity per segment ¹⁾	I _F = 2 mA	TDCY1050m	I _V		1.5		mcd
		TDCY1060m	I _V		1.5		mcd
	I _F = 10 mA	TDCY1050m	I _V	4.0	8.0		mcd
		TDCY1060m	I _V	4.0	8.0		mcd
Luminous intensity of colon	I _F = 2 mA	TDCY1050m	I _V		0.4		mcd
		TDCY1060m	I _V		0.4		mcd
	I _F = 10 mA	TDCY1050m	I _V	0.5	1.0		mcd
		TDCY1060m	I _V	0.5	1.0		mcd
Dominant wavelength	I _F = 20 mA		λ _d		589		nm
Peak wavelength	I _F = 20 mA		λ _p		591		nm
Spectral bandwidth	I _F = 20 mA		Δλ		15		nm
Forward voltage	I _F = 20 mA		V _F		2.0	2.4	V
Reverse current	V _R = 5 V		I _R			10	μA

Note¹⁾ I_{Vmin} and I_V groups are mean values of all segments (a to g, D1 to D4),
matching factor within segments is ≥ 0.5, excluding decimal points and colon.



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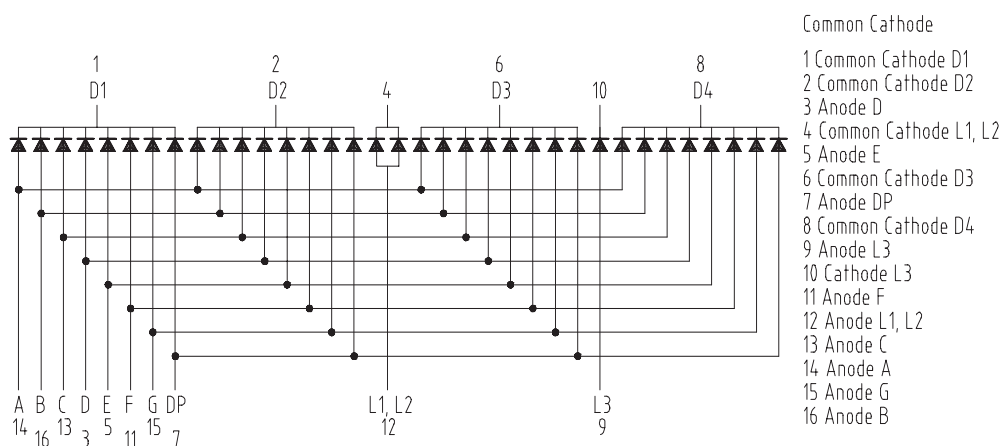
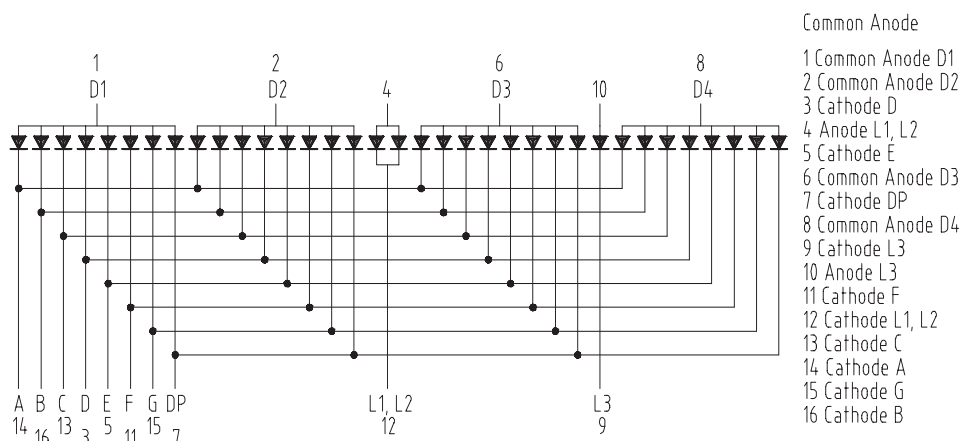
Green

TDCG1050m/ TDCG1060m

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity per segment ¹⁾	$I_F = 2 \text{ mA}$	TDCG1050m	I_V		1.0		mcd
		TDCG1060m	I_V		1.0		mcd
	$I_F = 10 \text{ mA}$	TDCG1050m	I_V	2.8	4.0		mcd
		TDCG1060m	I_V	2.8	4.0		mcd
Luminous intensity of colon	$I_F = 2 \text{ mA}$	TDCG1050m	I_V		0.2		mcd
		TDCG1060m	I_V		0.2		mcd
	$I_F = 10 \text{ mA}$	TDCG1050m	I_V	0.5	1.2		mcd
		TDCG1060m	I_V	0.5	1.2		mcd
Dominant wavelength	$I_F = 20 \text{ mA}$		λ_d	562	573	575	nm
Peak wavelength	$I_F = 20 \text{ mA}$		λ_p		575		nm
Spectral bandwidth	$I_F = 20 \text{ mA}$		$\Delta\lambda$		20		nm
Forward voltage	$I_F = 20 \text{ mA}$		V_F		2.0	2.4	V
Reverse current	$V_R = 5 \text{ V}$		I_R			10	μA

Note¹⁾ $I_{V\min}$ and I_V groups are mean values of all segments (a to g, D1 to D4),
matching factor within segments is ≥ 0.5 , excluding decimal points and colon.

Pinning



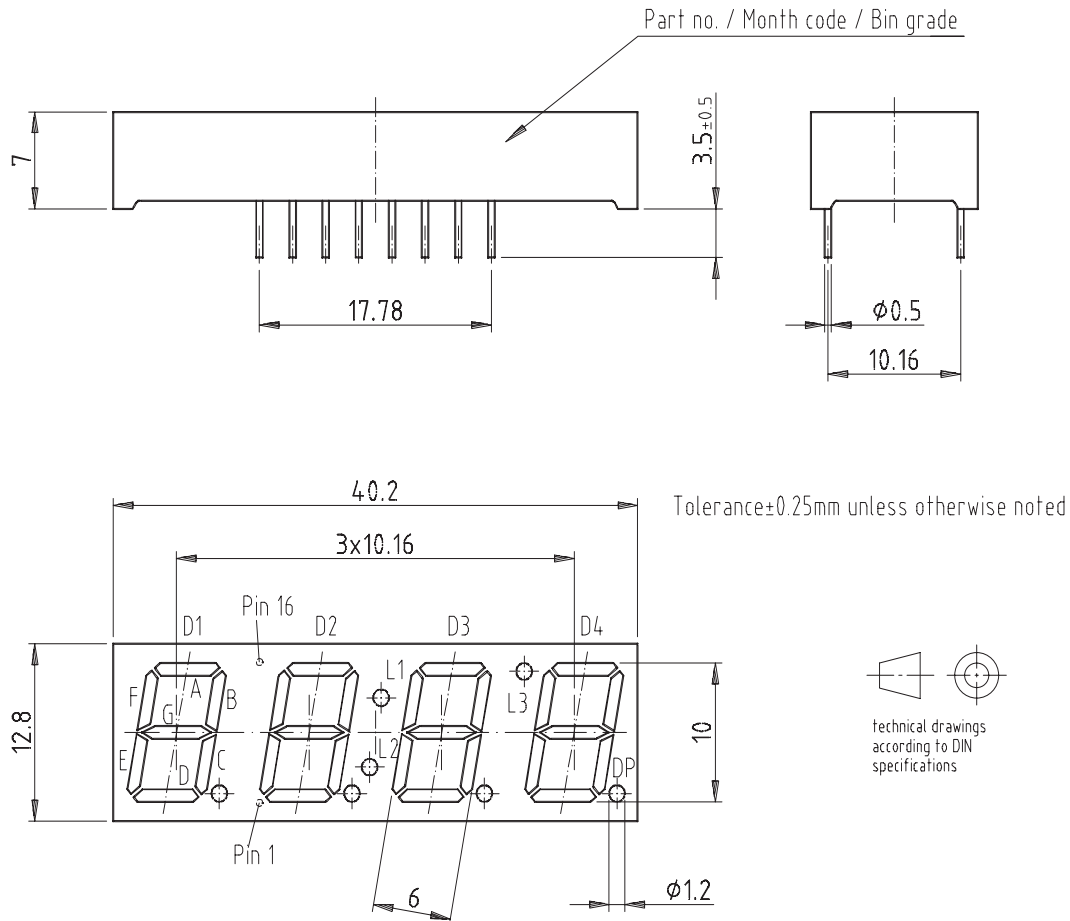
Drawing-No.: 6.544-5332.01-4 Bl. 2

Issue: 1; 20.02.02

16715



Package Dimensions in mm



Drawing-No.: 6.544-5332.01-4 Bl. 1
Issue: 3; 27.02.02

16764



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

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